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A Product Line of **Diodes Incorporated**

ZXMS6005DG

60V N-CHANNEL SELF PROTECTED ENHANCEMENT MODE INTELLIFET[®] MOSFET

Product Summary

- Continuous drain source voltage 200mΩ
- On-state resistance
- Nominal load current ($V_{IN} = 5V$) 2.8A 490mJ
- Clamping Energy

Description

The ZXMS6005DG is a self protected low side MOSFET with logic level input. It integrates over-temperature, over-current, over-voltage (active clamp) and ESD protected logic level functionality. The ZXMS6005DG is ideal as a general purpose switch driven from 3.3V or 5V microcontrollers in harsh environments where standard MOSFETs are not rugged enough.

SOT-223

Top View

60V

Applications

- Lamp Driver
- Motor Driver
- **Relay Driver**
- Solenoid Driver

Features and Benefits

- Compact high power dissipation package
- Low input current
- Logic Level Input (3.3V and 5V)
- Short circuit protection with auto restart
- Over voltage protection (active clamp)
- Thermal shutdown with auto restart
- Over-current protection Input Protection (ESD)
- High continuous current rating
- Lead-Free Finish; RoHS compliant (Note 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3) Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

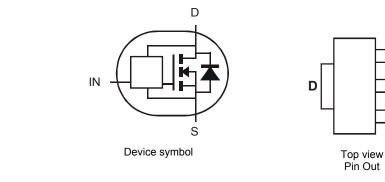
- Case: SOT-223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0

S

D

IN

- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish
- Weight: 0.112 grams (approximate)



Ordering Information (Note 4)

| Product | Marking | Reel size (inches) | Tape width (mm) | Quantity per reel |
|--------------|-----------|--------------------|-----------------|-------------------|
| ZXMS6005DGTA | ZXMS6005D | 7 | 12 | 1,000 |

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied. 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

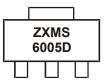
and Lead-free.

Notes:

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



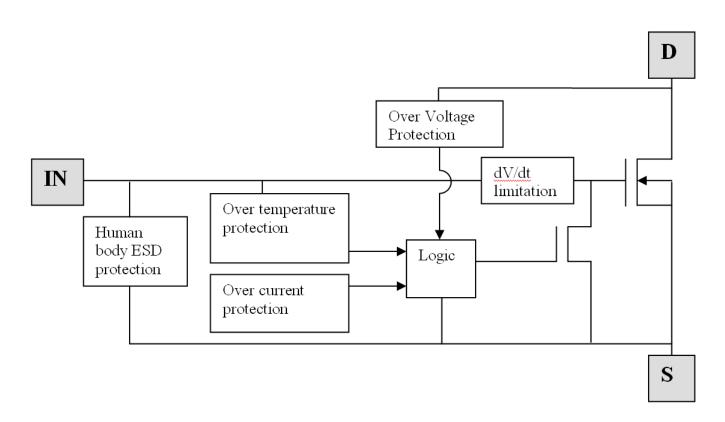
ZXMS6005D = Product type Marking Code

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Functional Block Diagram



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Units |
|---|---------------------|------------------------------------|-------|
| Continuous Drain-Source Voltage | V _{DS} | 60 | V |
| Drain-Source Voltage for Short Circuit Protection | V _{DS(SC)} | 24 | V |
| Continuous Input Voltage | V _{IN} | -0.5 +6 | V |
| Continuous Input Current @-0.2V \leq V _{IN} \leq 6V Continuous Input Current @V _{IN} < -0.2V or V _{IN} > 6V | l _{iN} | No limit I _{IN} ≤2 | mA |
| Pulsed Drain Current @V _{IN} = 3.3V | I _{DM} | 5 | А |
| Pulsed Drain Current @V _{IN} = 5V | I _{DM} | 6 | А |
| Continuous Source Current (Body Diode) (Note 5) | Is | 2.5 | А |
| Pulsed Source Current (Body Diode) | I _{SM} | 10 | А |
| Unclamped Single Pulse Inductive Energy, T _J = +25°C, I _D = 0.5A, V _{DD} = 24V | E _{AS} | 490 | mJ |
| Electrostatic Discharge (Human Body Model) | V _{ESD} | 4000 | V |
| Charged Device Model | V _{CDM} | 1000 | V |

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Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Units |
|--|------------------|-------------|------------|
| Power Dissipation at $T_A = +25^{\circ}C$ (Note 5) Linear Derating Factor | PD | 1.3 10.4 | W mW/°C |
| Power Dissipation at $T_A = +25^{\circ}C$ (Note 6) Linear Derating Factor | P _D | 3.0 24 | W mW/°C |
| Thermal Resistance, Junction to Ambient (Note 5) | R _{0JA} | 96 | °C/W |
| Thermal Resistance, Junction to Ambient (Note 6) | R _{0JA} | 42 | °C/W |
| Thermal Resistance, Junction to Case (Note 7) | Rejc | 12 | °C/W |
| Operating Temperature Range | TJ | -40 to +150 | °C |
| Storage Temperature Range | T _{STG} | -55 to +150 | °C |

Notes: 5. For a device surface mounted on 15mm x 15mm single sided 1oz weight copper on 1.6mm FR4 board, in still air conditions. 6. For a device surface mounted on 50mm x 50mm single sided 2oz weight copper on 1.6mm FR4 board, in still air conditions.

For a device surface mounted on somm x somm single sided 202 weight copper on 1.5mm FR4 board, in still
 Thermal resistance between junction and the mounting surfaces of drain and source pins.

Recommended Operating Conditions

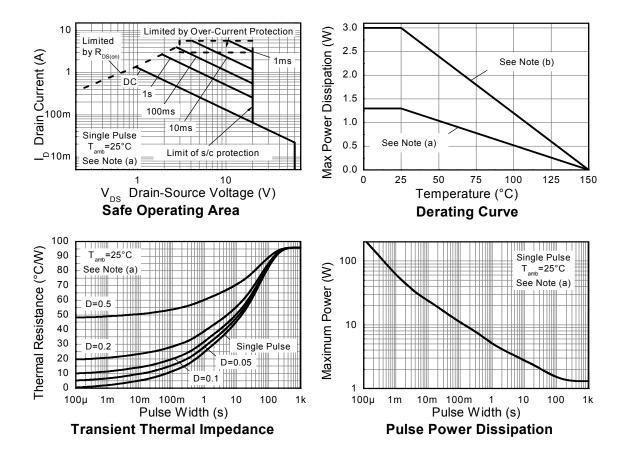
The ZXMS6005DG is optimized for use with μC operating from 3.3V and 5V supplies.

| Characteristic | Symbol | Min | Max | Unit |
|---|-----------------|-----|------|------|
| Input Voltage Range | V _{IN} | 0 | 5.5 | V |
| Ambient Temperature Range | T _A | -40 | +125 | °C |
| High Level Input Voltage for MOSFET to be on | VIH | 3 | 5.5 | V |
| Low level input voltage for MOSFET to be off | V _{IL} | 0 | 0.7 | V |
| Peripheral Supply Voltage (voltage to which load is referred) | VP | 0 | 24 | V |



A Product Line of Diodes Incorporated ZXMS6005DG

Thermal Characteristics



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Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|---|---------------------|-----|-------|-----|------|--|
| Static Characteristics | Gymbol | | 1.150 | Mux | Unit | |
| Drain-Source Clamp Voltage | V _{DS(AZ)} | 60 | 65 | 70 | V | I _D = 10mA |
| Off State Durin Summent | | _ | - | 1 | μA | V _{DS} = 12V, V _{IN} = 0V |
| Off State Drain Current | IDSS | _ | - | 2 | | V _{DS} = 36V, V _{IN} = 0V |
| Input Threshold Voltage | V _{IN(th)} | 0.7 | 1 | 1.5 | V | $V_{DS} = V_{GS}$, $I_D = 1mA$ |
| Input Current | | - | 60 | 100 | μA | V _{IN} = +3V |
| input Current | I _{IN} | - | 120 | 200 | | V _{IN} = +5V |
| Input Current While Over Temperature Active | - | I | _ | 300 | μA | $V_{IN} = +5V$ |
| Static Drain-Source On-State Resistance | D | I | 170 | 250 | mΩ | $V_{IN} = +3V, I_D = 1A$ |
| | R _{DS(on)} | I | 150 | 200 | | V _{IN} = +5V, I _D = 1A |
| Continuous Drain Current (Note 4) | | 1.4 | _ | _ | A | V _{IN} = 3V; T _A = +25°C |
| | 1- | 1.6 | _ | - | | $V_{IN} = 5V; T_A = +25^{\circ}C$ |
| Continuous Drain Current (Note 5) | I _D | 1.9 | _ | _ | | V _{IN} = 3V; T _A = +25°C |
| Continuous Drain Current (Note 5) | | 2.0 | _ | _ | | $V_{IN} = 5V; T_A = +25^{\circ}C$ |
| Current Limit (Note 7) | I _{D(LIM)} | 2.2 | 5 | - | A | $V_{IN} = +3V$ |
| | | 3.3 | 7 | - | | V _{IN} = +5V |
| Dynamic Characteristics | | | | | | |
| Turn On Delay Time | t _{d(on)} | - | 6 | - | | |
| Rise Time | tr | - | 14 | - | 110 | V _{DD} = 12V, I _D = 1A, V _{GS} = 5V |
| Turn Off Delay Time | t _{d(off)} | - | 34 | - | μs | |
| Fall Time | f _f | - | 19 | - |] | |
| Over-Temperature Protection | | | | | | |
| Thermal Overload Trip Temperature (Note 8) | T _{JT} | 150 | 175 | - | °C | _ |
| Thermal Hysteresis (Note 8) | f _f | _ | 10 | - | °C | - |

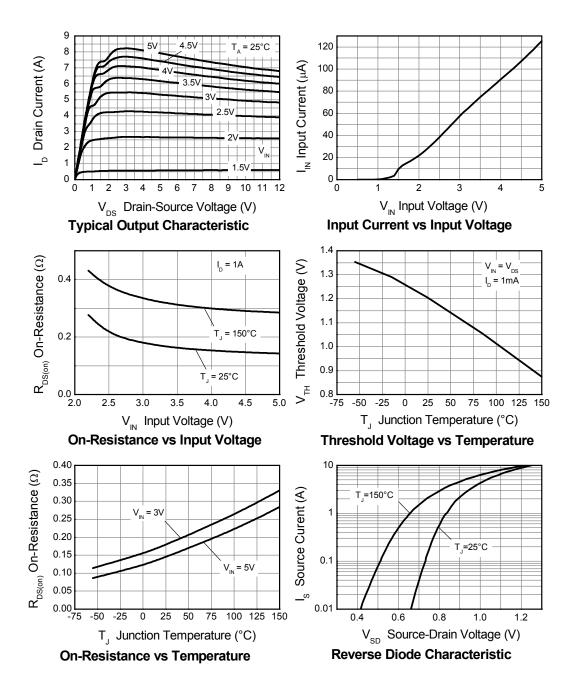
Notes: 7. The drain current is restricted only when the device is in saturation (see graph 'typical output characteristic'). This allows the device to be used in the fully on state without interference from the current limit. The device is fully protected at all drain currents, as the low power dissipation generated outside saturation makes current limit unnecessary.

8. Over-temperature protection is designed to prevent device destruction under fault conditions. Fault conditions are considered as "outside" normal operating range, so this part is not designed to withstand over-temperature for extended periods...



A Product Line of Diodes Incorporated ZXMS6005DG

Typical Characteristics







Typical Characteristics - Continued

Ω 2 _____0

-2

0

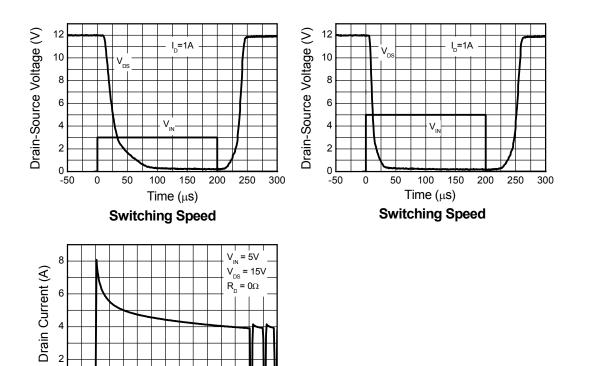
2

4

6

Time (ms)
Typical Short Circuit Protection

8



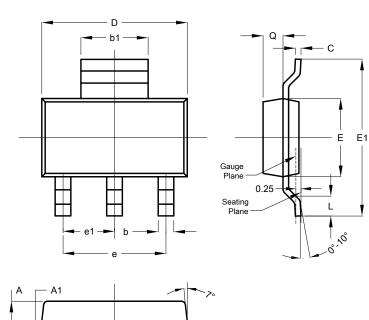
10

12



Package Outline Dimensions

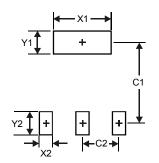
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



| | SOT223 | | | | | |
|-------|----------------------|------|------|--|--|--|
| Dim | Min | Мах | Тур | | | |
| Α | 1.55 | 1.65 | 1.60 | | | |
| A1 | 0.010 | 0.15 | 0.05 | | | |
| b | 0.60 | 0.80 | 0.70 | | | |
| b1 | 2.90 | 3.10 | 3.00 | | | |
| С | 0.20 | 0.30 | 0.25 | | | |
| D | 6.45 | 6.55 | 6.50 | | | |
| Е | 3.45 | 3.55 | 3.50 | | | |
| E1 | 6.90 | 7.10 | 7.00 | | | |
| е | - | - | 4.60 | | | |
| e1 | - | - | 2.30 | | | |
| L | 0.85 | 1.05 | 0.95 | | | |
| Q | 0.84 | 0.94 | 0.89 | | | |
| All [| All Dimensions in mm | | | | | |

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| X1 | 3.3 |
| X2 | 1.2 |
| Y1 | 1.6 |
| Y2 | 1.6 |
| C1 | 6.4 |
| C2 | 2.3 |

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ZXMS6005DG

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